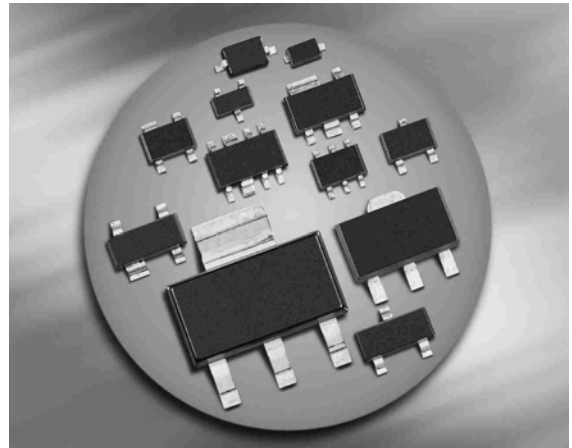


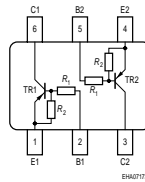
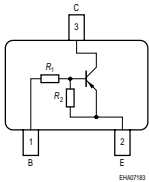
PNP Silicon Digital Transistor

- Switching circuit, inverter, interface circuit, driver circuit
- Built in bias resistor ($R_1 = 22k\Omega$, $R_2 = 22k\Omega$)
- For 6-PIN packages: two (galvanic) internal isolated transistors with good matching in one package



BCR191/F/L3
BCR191T/W

BCR191S



Type	Marking	Pin Configuration						Package
		1=B	2=E	3=C	-	-	-	
BCR191	W0s	1=B	2=E	3=C	-	-	-	SOT23
BCR191F	W0s	1=B	2=E	3=C	-	-	-	TSFP-3
BCR191L3	W0	1=B	2=E	3=C	-	-	-	TSLP-3-4
BCR191S	W0s	1=E1	2=B1	3=C2	4=E2	5=B2	6=C1	SOT363
BCR191T	W0s	1=B	2=E	3=C	-	-	-	SC75
BCR191W	W0s	1=B	2=E	3=C	-	-	-	SOT323

Maximum Ratings

Parameter	Symbol	Value	Unit
Collector-emitter voltage	V_{CEO}	50	V
Collector-base voltage	V_{CBO}	50	
Emitter-base voltage	V_{EBO}	10	
Input on voltage	$V_{i(on)}$	30	
Collector current	I_C	100	mA
Total power dissipation- BCR191, $T_S \leq 102^\circ\text{C}$ BCR191F, $T_S \leq 128^\circ\text{C}$ BCR191L3, $T_S \leq 135^\circ\text{C}$ BCR191S, $T_S \leq 115^\circ\text{C}$ BCR191T, $T_S \leq 109^\circ\text{C}$ BCR191W, $T_S \leq 124^\circ\text{C}$	P_{tot}	200 250 250 250 250 250	mW
Junction temperature	T_j	150	°C
Storage temperature	T_{stg}	150 ... -65	

Thermal Resistance

Parameter	Symbol	Value	Unit
Junction - soldering point ¹⁾	R_{thJS}		K/W
BCR191		≤ 240	
BCR191F		≤ 90	
BCR191L3		≤ 60	
BCR191S		≤ 140	
BCR191T		≤ 165	
BCR191W		≤ 105	

¹⁾For calculation of R_{thJA} please refer to Application Note Thermal Resistance

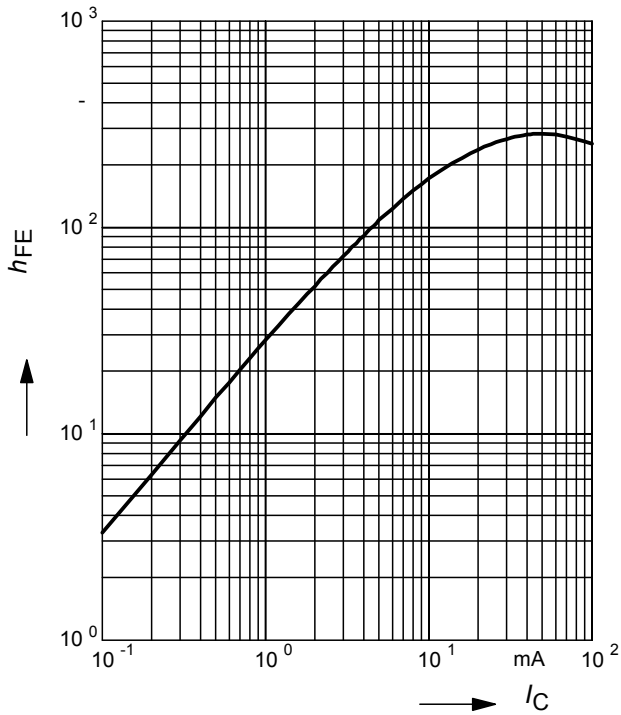
Electrical Characteristics at $T_A = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
DC Characteristics					
Collector-emitter breakdown voltage $I_C = 100 \mu\text{A}, I_B = 0$	$V_{(BR)CEO}$	50	-	-	V
Collector-base breakdown voltage $I_C = 10 \mu\text{A}, I_E = 0$	$V_{(BR)CBO}$	50	-	-	
Collector-base cutoff current $V_{CB} = 40 \text{ V}, I_E = 0$	I_{CBO}	-	-	100	nA
Emitter-base cutoff current $V_{EB} = 10 \text{ V}, I_C = 0$	I_{EBO}	-	-	350	μA
DC current gain ¹⁾ $I_C = 5 \text{ mA}, V_{CE} = 5 \text{ V}$	h_{FE}	50	-	-	-
Collector-emitter saturation voltage ¹⁾ $I_C = 10 \text{ mA}, I_B = 0,5 \text{ mA}$	V_{CEsat}	-	-	0,3	V
Input off voltage $I_C = 100 \mu\text{A}, V_{CE} = 5 \text{ V}$	$V_{i(off)}$	0,8	-	1,5	
Input on voltage $I_C = 2 \text{ mA}, V_{CE} = 0,3 \text{ V}$	$V_{i(on)}$	1	-	2,5	
Input resistor	R_1	15	22	29	$\text{k}\Omega$
Resistor ratio	R_1/R_2	0,9	1	1,1	-
AC Characteristics					
Transition frequency $I_C = 10 \text{ mA}, V_{CE} = 5 \text{ V}, f = 100 \text{ MHz}$	f_T	-	200	-	MHz
Collector-base capacitance $V_{CB} = 10 \text{ V}, f = 1 \text{ MHz}$	C_{cb}	-	3	-	pF

¹Pulse test: $t < 300 \mu\text{s}$; $D < 2\%$

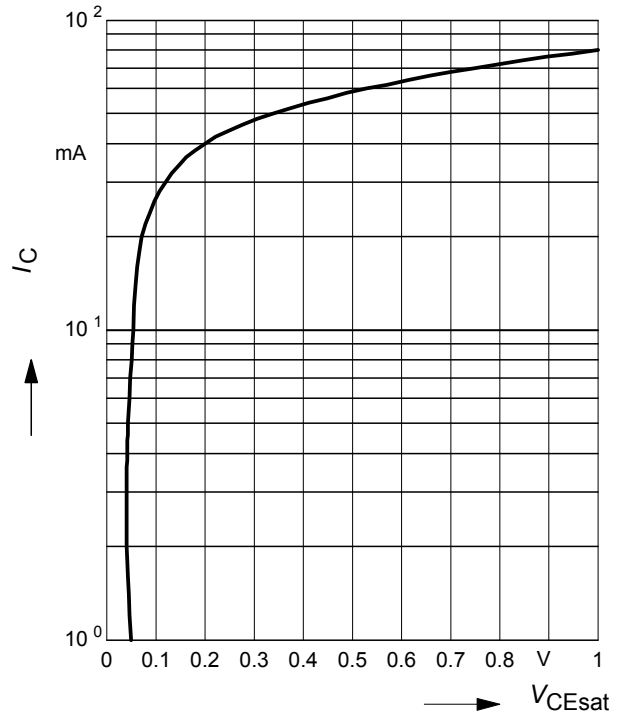
DC current gain $h_{FE} = f(I_C)$

$V_{CE} = 5\text{ V}$ (common emitter configuration)



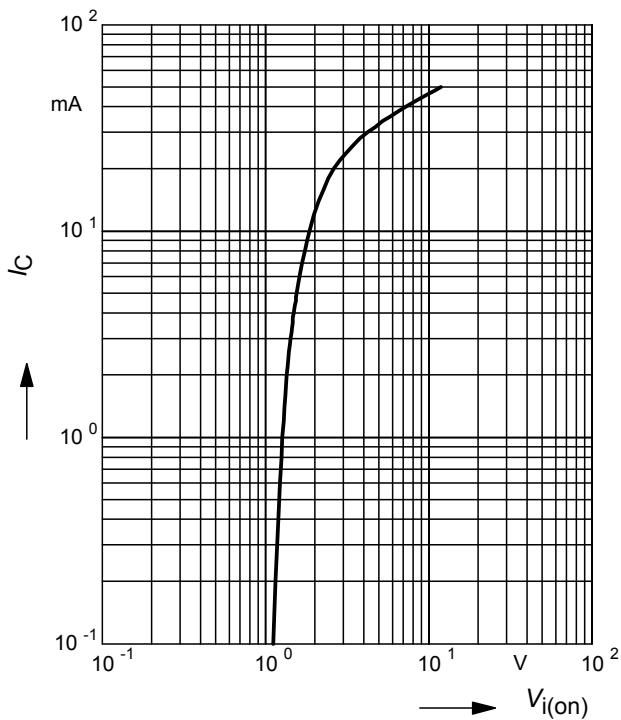
Collector-emitter saturation voltage

$V_{CEsat} = f(I_C), h_{FE} = 20$



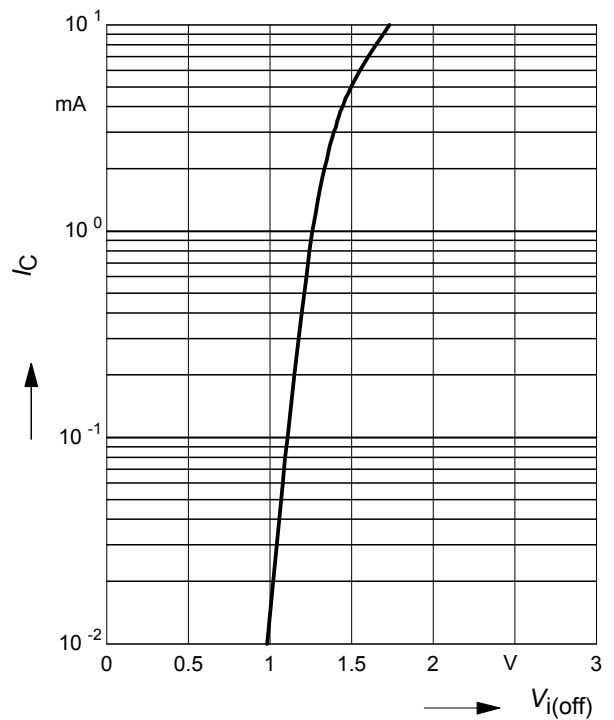
Input on Voltage $V_{i(on)} = f(I_C)$

$V_{CE} = 0.3\text{ V}$ (common emitter configuration)



Input off voltage $V_{i(off)} = f(I_C)$

$V_{CE} = 5\text{ V}$ (common emitter configuration)



Total power dissipation $P_{tot} = f(T_S)$

BCR191



Total power dissipation $P_{tot} = f(T_S)$

BCR191F



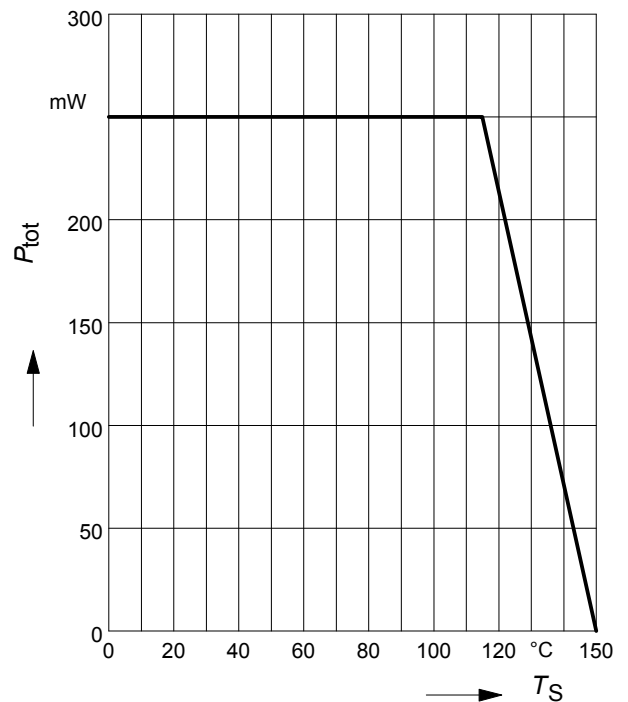
Total power dissipation $P_{tot} = f(T_S)$

BCR191L3



Total power dissipation $P_{tot} = f(T_S)$

BCR191S



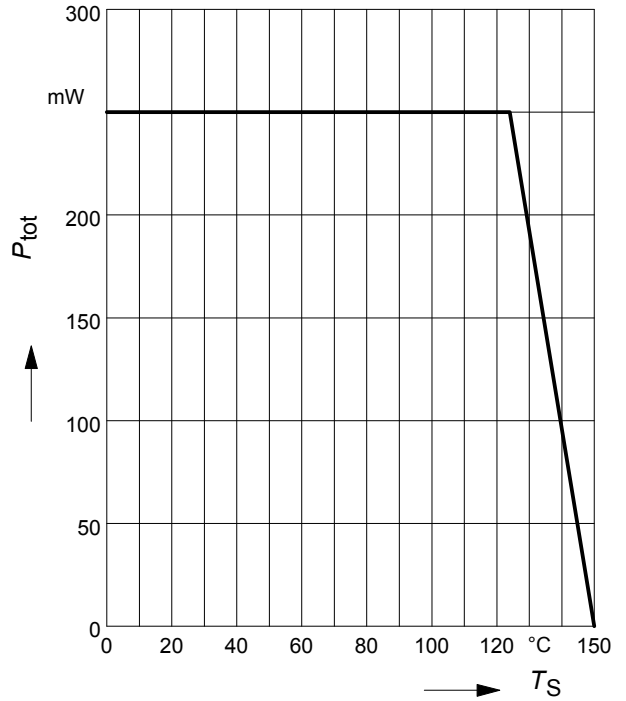
Total power dissipation $P_{tot} = f(T_S)$

BCR191T



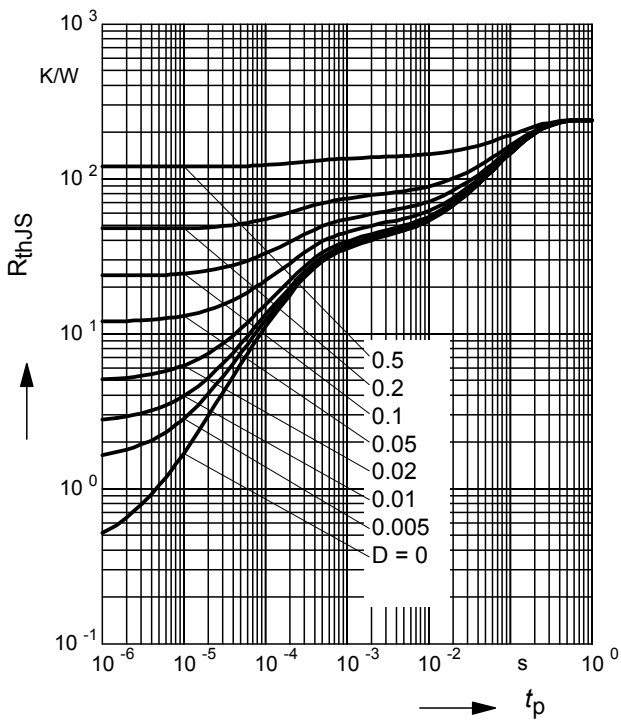
Total power dissipation $P_{tot} = f(T_S)$

BCR191W



Permissible Pulse Load $R_{thJS} = f(t_p)$

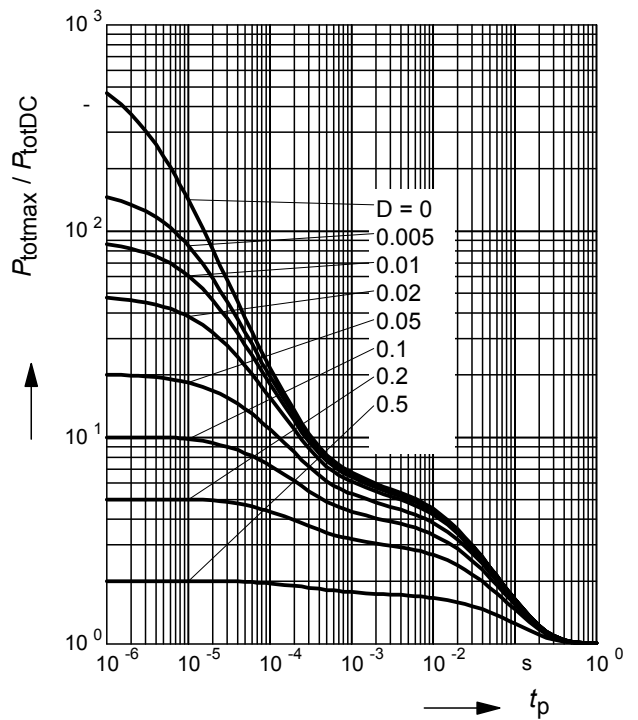
BCR191



Permissible Pulse Load

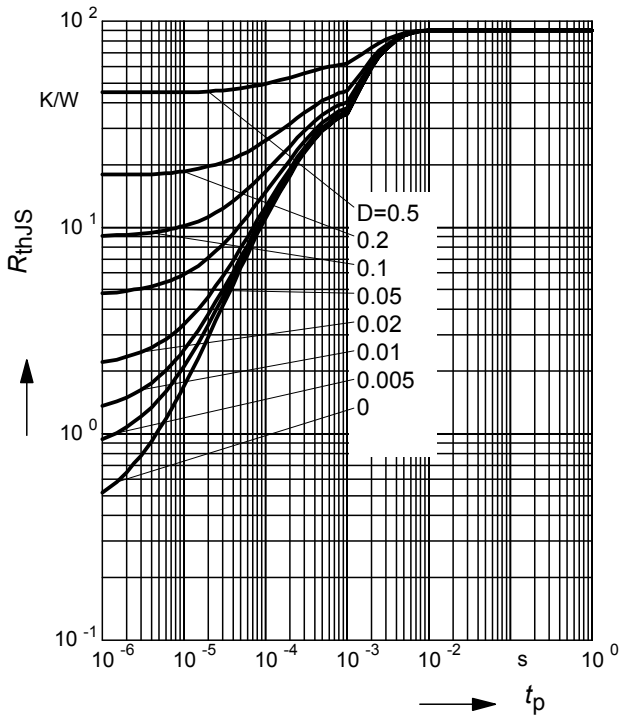
$P_{totmax}/P_{totDC} = f(t_p)$

BCR191



Permissible Puls Load $R_{thJS} = f(t_p)$

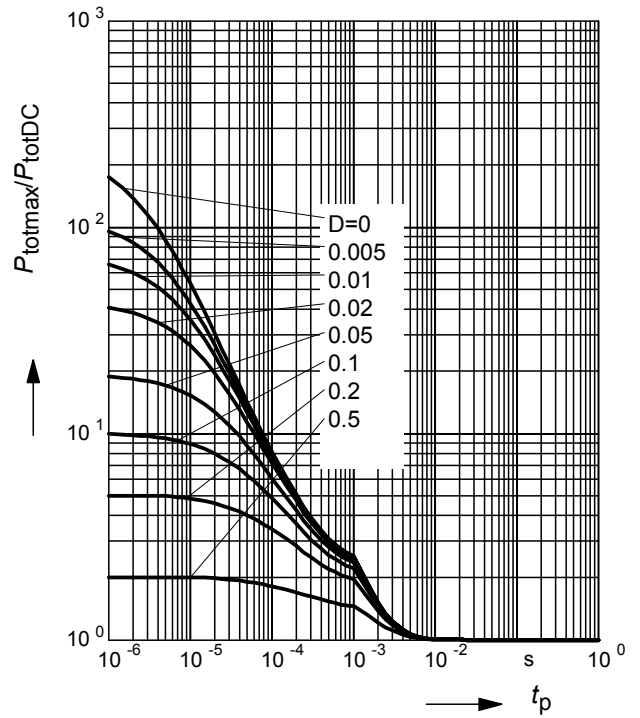
BCR191F



Permissible Pulse Load

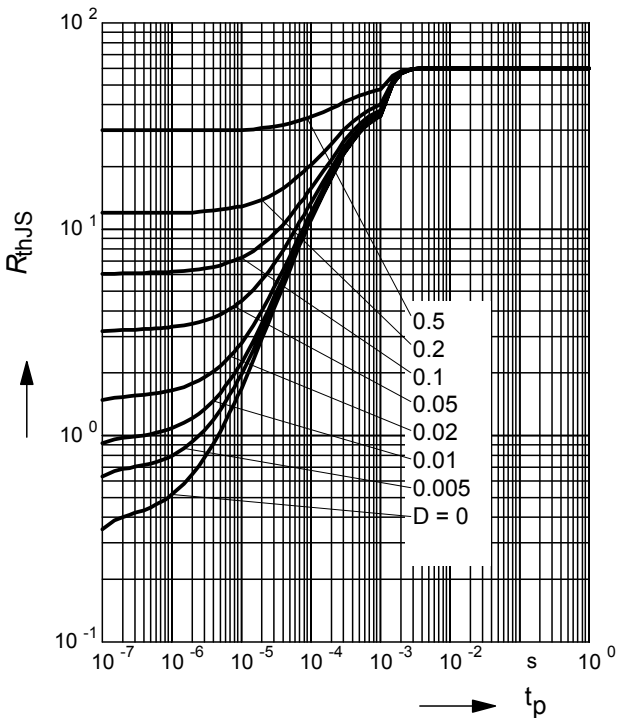
$P_{totmax}/P_{totDC} = f(t_p)$

BCR191F



Permissible Puls Load $R_{thJS} = f(t_p)$

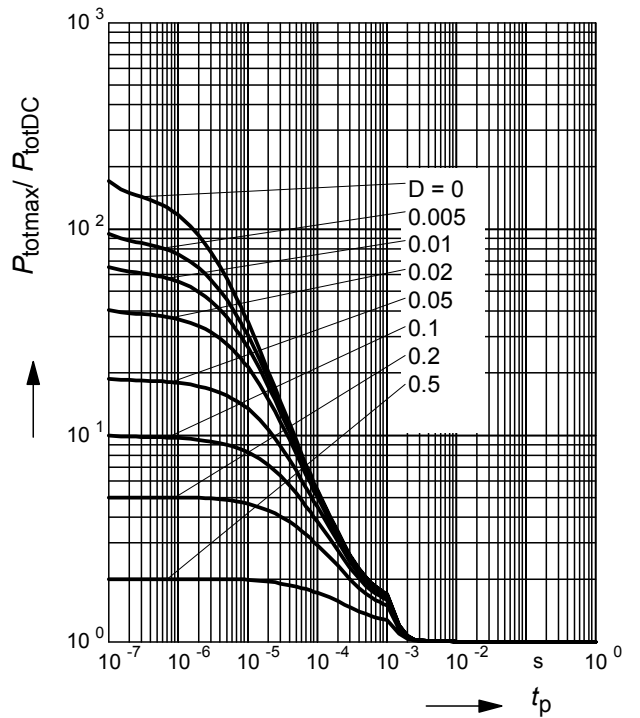
BCR191L3



Permissible Pulse Load

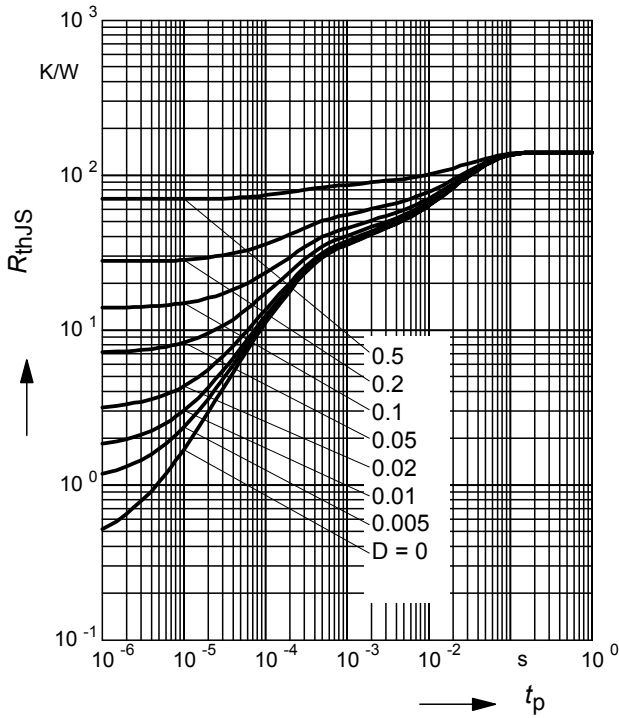
$P_{totmax}/P_{totDC} = f(t_p)$

BCR191L3



Permissible Puls Load $R_{thJS} = f(t_p)$

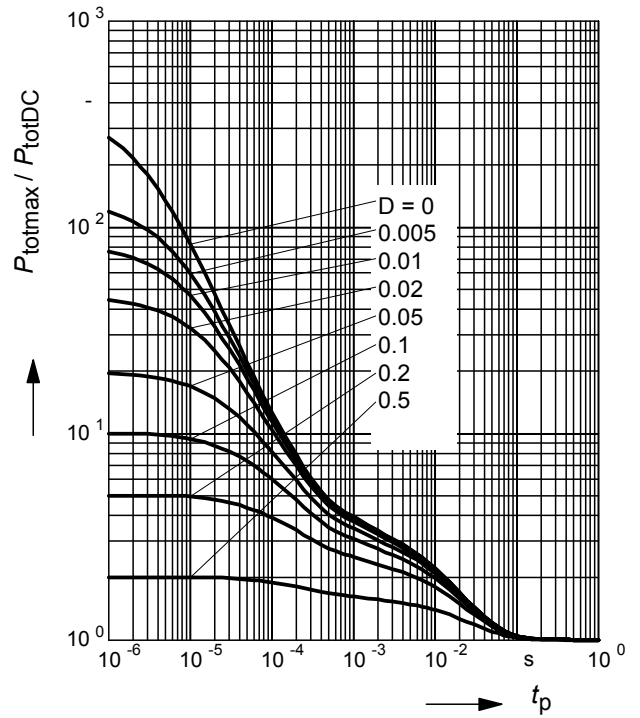
BCR191S



Permissible Pulse Load

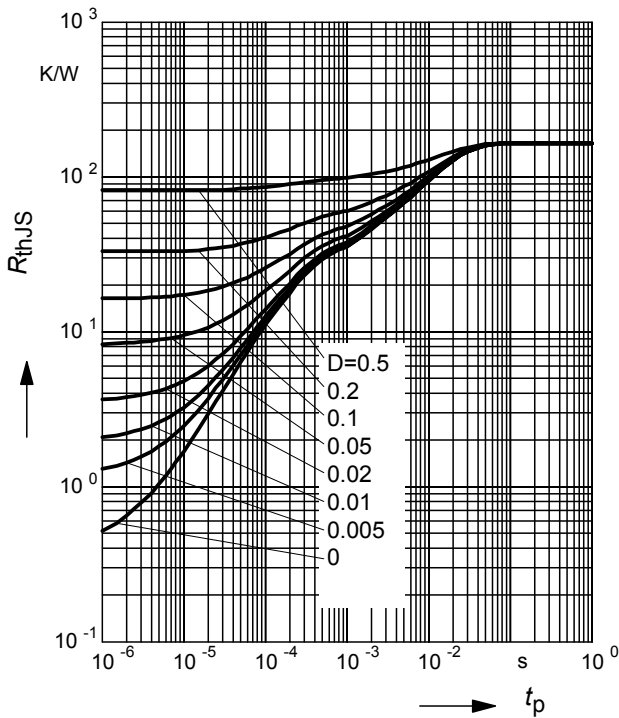
$P_{totmax}/P_{totDC} = f(t_p)$

BCR191S



Permissible Puls Load $R_{thJS} = f(t_p)$

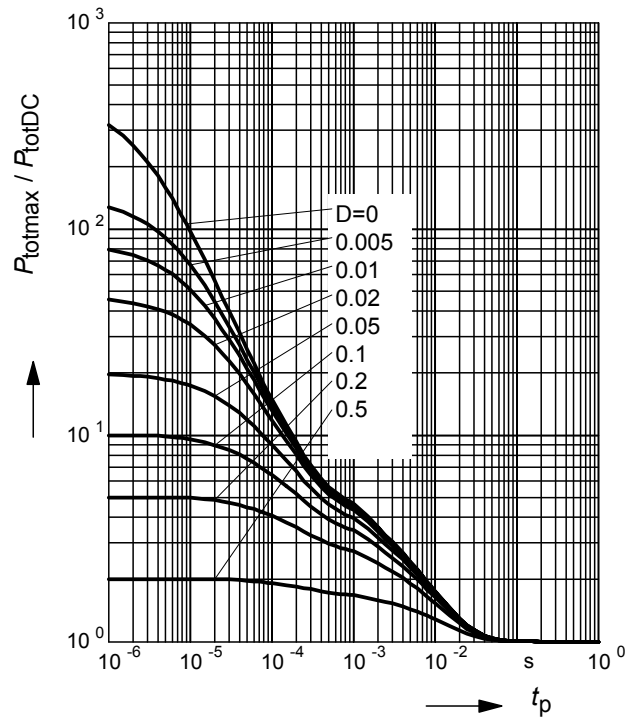
BCR191T



Permissible Pulse Load

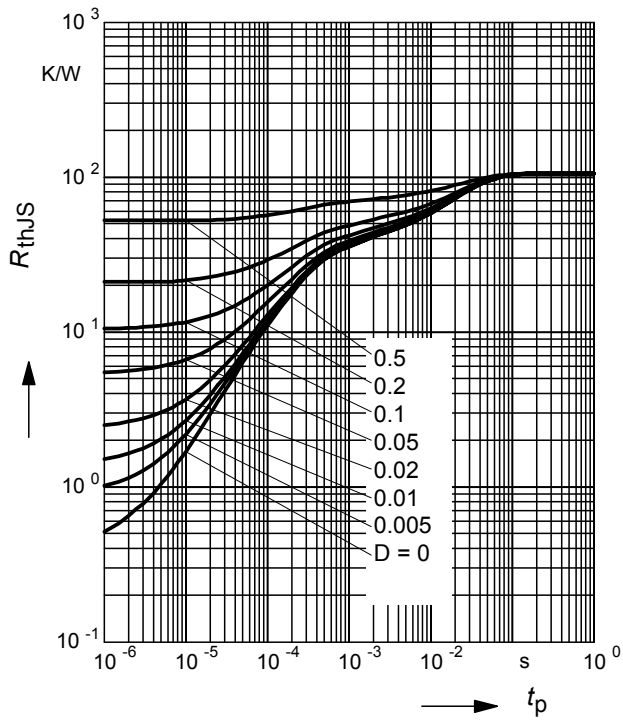
$P_{totmax}/P_{totDC} = f(t_p)$

BCR191T



Permissible Puls Load $R_{thJS} = f(t_p)$

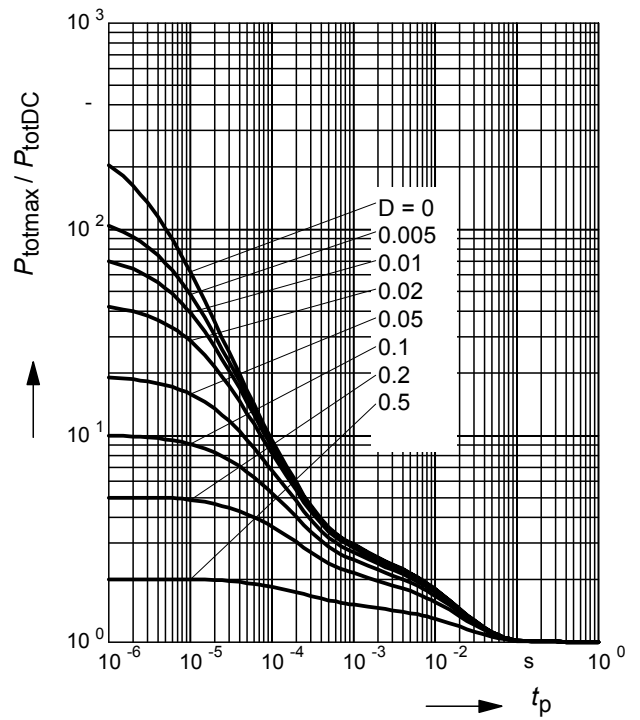
BCR191W



Permissible Pulse Load

$P_{totmax}/P_{totDC} = f(t_p)$

BCR191W





LittleDiode supplies new, hard to find or obsolete electronic components and semiconductors all over the world.

With over two million different components listed you are sure to find the part you need.

Feel free to visit us today at our online store:

LittleDiode.com

Looking forward to providing you with the best possible service.